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PBSS9110T,215

Nexperia

Bipolar Transistors - BJT TRANS BISS TAPE-7

Any questions, please feel free to contact us. info@kaimte.com

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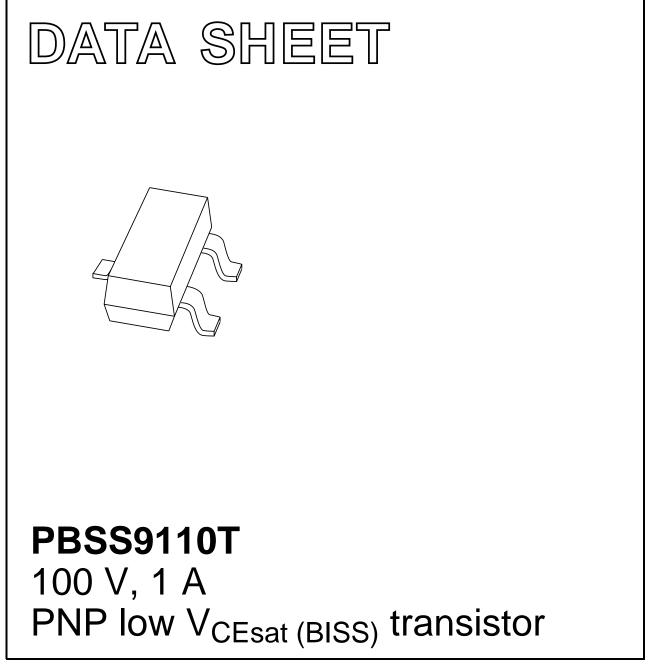
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Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2004 May 06 2004 May 13



100 V, 1 A PNP low V_{CEsat (BISS)} transistor

FEATURES

- SOT23 package
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability: I_C and I_{CM}
- · Higher efficiency leading to less heat generation

APPLICATIONS

- Major application segments
 - Automotive 42 V power
 - Telecom infrastructure
- Industrial
- DC-to-DC conversion
- Peripheral drivers
 - Driver in low supply voltage applications (e.g. lamps and LEDs).
 - Inductive load driver (e.g. relays, buzzers and motors).

DESCRIPTION

PNP low V_{CEsat} transistor in a SOT23 plastic package. NPN complement: PBSS8110T.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾		
PBSS9110T	*U7		

Note

1. * = p: Made in Hong Kong.

* = t: Made in Malaysia.

* = W: Made in China.

ORDERING INFORMATION

TYPE NUMBER		PACKAGE	
	NAME DESCRIPTION		VERSION
PBSS9110T	-	plastic surface mounted package; 3 leads	SOT23

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT	
V _{CEO}	collector-emitter voltage	-100	V	
I _C	collector current (DC) -1		А	
I _{CM}	repetitive peak collector current	-3	A	
R _{CEsat}	equivalent on-resistance	320	mΩ	

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector

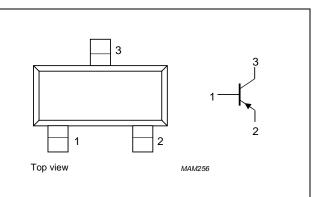


Fig.1 Simplified outline (SOT23) and symbol.

PBSS9110T

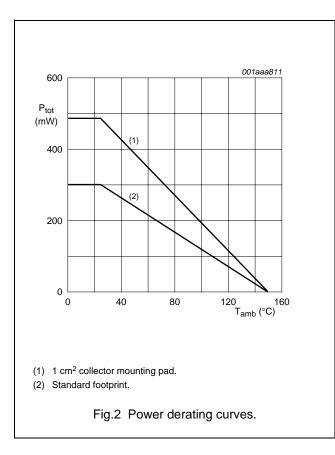
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-120	V
V _{CEO}	collector-emitter voltage	open base	_	-100	V
V _{EBO}	emitter-base voltage	open collector	_	-5	V
I _C	collector current (DC)		_	-1	А
I _{CM}	peak collector current	limited by T _{j(max)}	-	-3	А
Ι _Β	base current (DC)		_	-300	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$; note 1	_	300	mW
		$T_{amb} \le 25 \ ^{\circ}C$; note 2	_	480	mW
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

Notes

- 1. Device mounted on a printed-circuit board, single-sided copper, tin-plated, standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated and 1 cm² collector mounting pad.



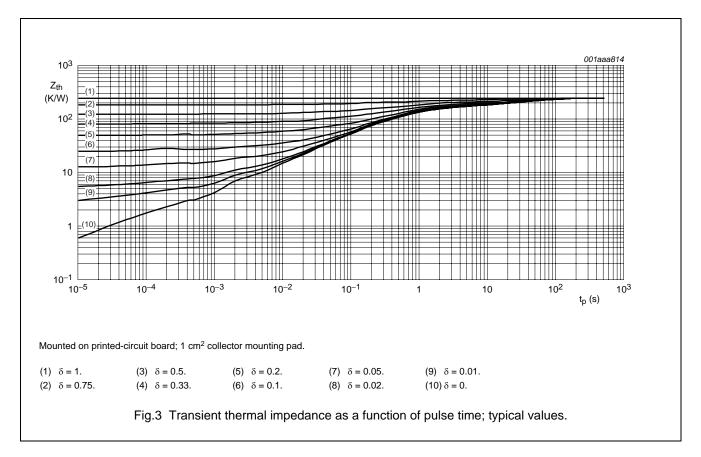
PBSS9110T

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to	in free air; note 1	417	K/W
	ambient	in free air; note 2	260	K/W

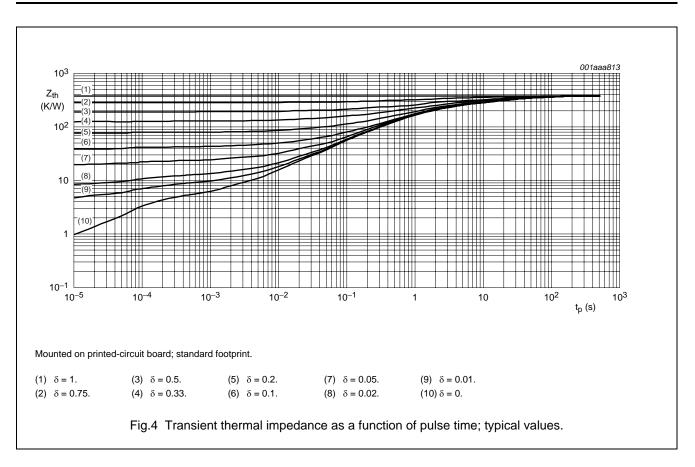
Notes

- 1. Device mounted on a printed-circuit board, single-sided copper, tin-plated and standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated and 1 cm² collector mounting pad.



Product data sheet

100 V, 1 A PNP low $V_{CEsat (BISS)}$ transistor



PBSS9110T

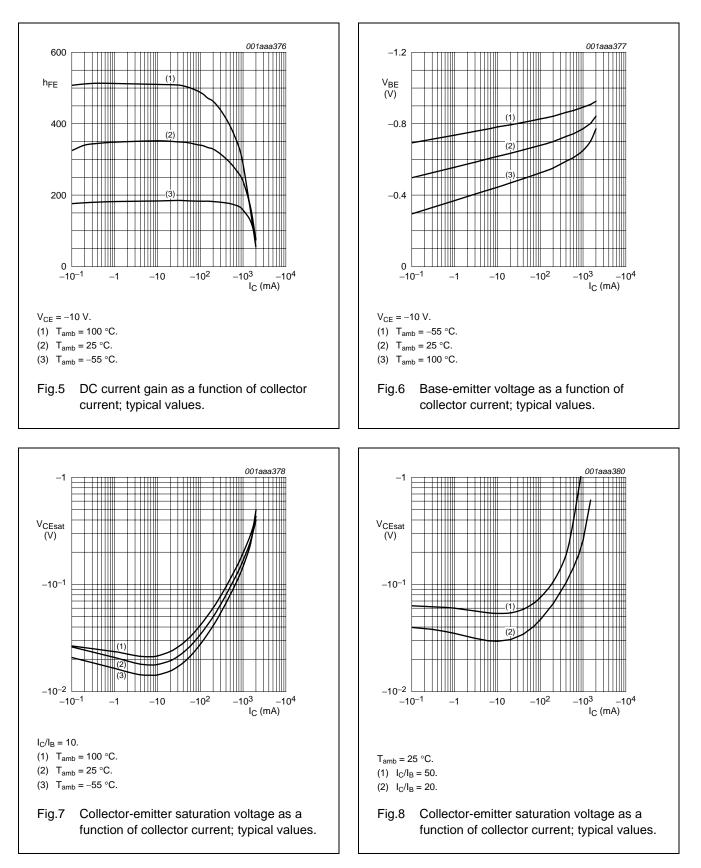
CHARACTERISTICS

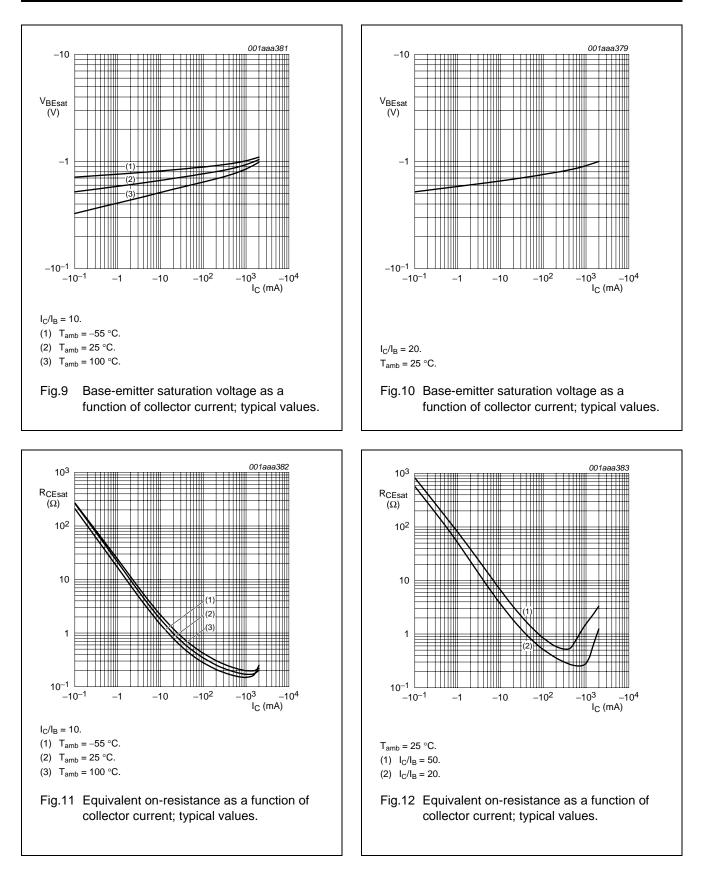
 $T_j = 25 \ ^{\circ}C$ unless otherwise specified.

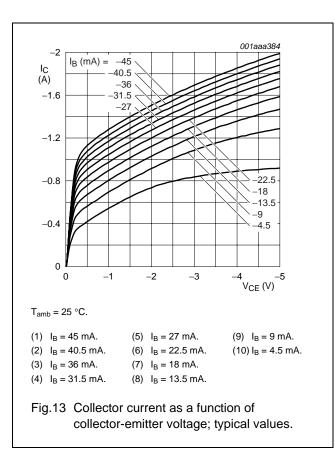
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -80 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	_	-	-100	nA
		$V_{CB} = -80 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	-	-50	μA
I _{CES}	collector-emitter cut-off current	$V_{CE} = -80 \text{ V}; \text{ V}_{BE} = 0 \text{ A}$	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -4 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -1 \text{ mA}$	150	-	-	
		$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -250 \text{ mA}$	150	-	-	
		$V_{CE} = -5 \text{ V}; I_{C} = -500 \text{ mA}; \text{ note } 1$	150	-	450	
		$V_{CE} = -5 \text{ V}; I_{C} = -1 \text{ A}; \text{ note } 1$	125	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = -250 \text{ mA}; I_{\rm B} = -25 \text{ mA}$	-	-	-120	mV
		$I_{C} = -500 \text{ mA}; I_{B} = -50 \text{ mA}$	-	-	-180	mV
		$I_{C} = -1 \text{ A}; I_{B} = -100 \text{ mA}; \text{ note } 1$	-	-	-320	mV
R _{CEsat}	equivalent on-resistance	$I_{C} = -1 \text{ A}; I_{B} = -100 \text{ mA}; \text{ note } 1$	-	170	320	mΩ
V _{BEsat}	base-emitter saturation voltage	$I_{\rm C} = -1$ A; $I_{\rm B} = -100$ mA	-	-	-1.1	V
V _{BEon}	base-emitter turn-on voltage	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -1 \text{ A}$	-	-	-1	V
f _T	transition frequency	V _{CE} = -10 V; I _C = -50 mA; f = 100 MHz	100	-	-	MHz
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz	-	-	17	pF

Note

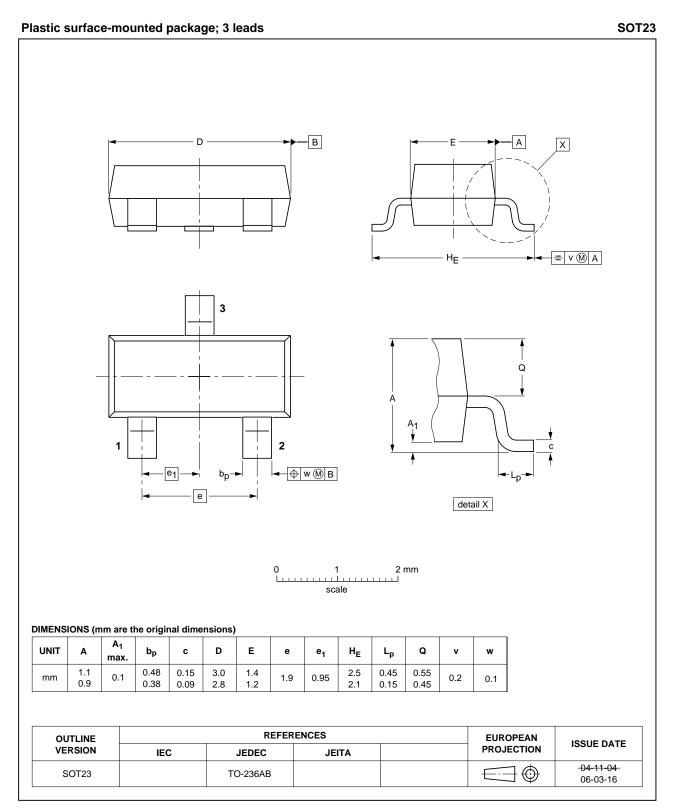
1. Pulse test: $t_p \leq 300~\mu s; ~\delta \leq 0.02.$







PACKAGE OUTLINE



PBSS9110T

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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